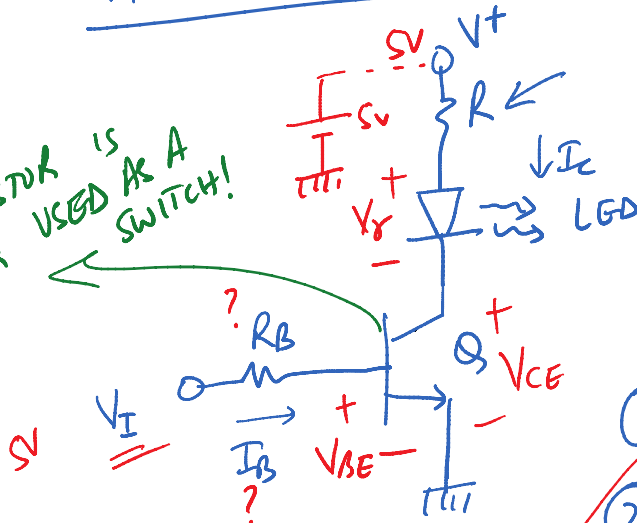


LECTURE -27

APPLICATION

TRANSISTOR IS BEING USED AS A SWITCH!



- LED
- ① LARGER TURN ON VOLTAGE THAN STANDARD P-N DIODE
 - ② NEEDS LARGER CURRENT

LED REQUIREMENT

- ① $V_\gamma \rightarrow$ LED TURN-ON VOLTAGE
- ② $I_\gamma(\text{MIN}) \rightarrow$ MIN. CURRENT REQUIRED TO GET THE DESIRED/SPECIFIED LUMINOSITY
- ③ $I_\gamma(\text{MAX}) \rightarrow$ CANNOT EXCEED $I_{\gamma(\text{MAX})}$

$I_{C(\text{REQD})} = 12\text{mA}$
 $\beta = 50 \leftarrow$ ACTIVE REGION
 $V_{BE(\text{on})} = 0.7\text{V}$
 $V_{CE(\text{SAT})} = 0.2\text{V}$

\therefore WE NEED A CURRENT LIMITING RESISTOR

$V_I = 0\text{V}$ Q IS OFF $I_B = 0$ $I_C = 0$ LED IS OFF
 $V_I = 5\text{V}$ Q IS ON TRANSISTOR IS DRIVEN INTO SAT. GOAL

$V_{CE} = V_{CE(\text{SAT})} = 0.2\text{V}$

KVL CE LOOP

$-5 + I_C R + V_\gamma + V_{CE(\text{SAT})} = 0$

$R = \frac{5 - V_\gamma - V_{CE(\text{SAT})}}{I_C} = \frac{5 - (1.5 + 0.2)}{12\text{mA}}$

= 2750

$$I_C = \beta I_B \rightarrow \text{ONLY VALID IN ACTIVE REGION}$$

IN SATURATION

$$I_C = \beta_{\text{FORCED}} I_B$$

$\beta_{\text{FORCED}} < \beta (\text{ACTIVE})$
 $\beta \downarrow = \infty$
CHOOSE

SAY $\beta_{\text{FORCED}} = 20$ [CHOICE]

* IF $\beta_{\text{FORCED}} \uparrow$ \downarrow $I_B \downarrow$ $R_B \uparrow$
NEED TO INCREASE I_B AND DECREASE R_B
 $\therefore \beta_f \downarrow \downarrow$

$$\frac{I_C}{I_B} = \beta_{\text{FORCED}} = 20 \quad I_C = \boxed{12 \text{ mA}}$$

$$I_B = \boxed{0.6 \text{ mA}}$$

KVL BE LOOP

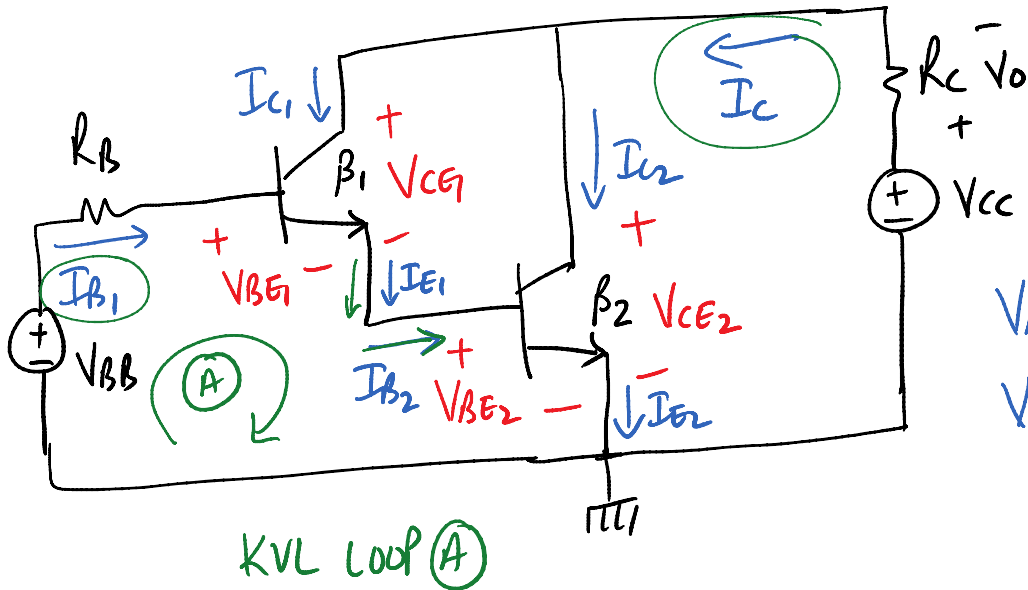
$$-V_I + I_B R_B + V_{BE(\text{ON})} = 0$$

$$R_B = \frac{V_I - 0.7}{0.6 \text{ mA}} = \boxed{7.17 \text{ k}\Omega}$$

$$P_T = I_B V_{BE(\text{on})} + I_C V_{CE} = (0.6\text{mA})(0.7) + (12\text{mA})(0.2) \\ = \underline{\underline{2.82\text{mW}}}$$

DARLINGTON AMPLIFIER AND ANALYSIS

$\beta_{\text{OVERALL}}??$



$$V_{BE} = 0.7 \text{ V} = V_{to}$$

$$V_{BE1} = V_{BE2} = V_{to}$$

KVL LOOP (A)

$$-V_{BB} + I_{B1} R_B + V_{BE1} + V_{BE2} = 0$$

$$I_{B1} = \frac{V_{BB} - 2V_{to}}{R_B}$$

ASSUME ACTIVE REGION!

$$I_{C1} = \beta_1 I_{B1} = \left(\frac{\beta_1}{R_B} (V_{BB} - 2V_{to}) \right)$$

$$I_{C2} = \beta_2 I_{B2} = \beta_2 I_{E1} = \beta_2 \frac{I_{C1}}{\alpha_1}$$

$$= \frac{\beta_2 \beta_1}{\alpha_1 R_B} (V_{BB} - 2V_{to})$$

$$\beta_1 \approx \alpha_1$$

α, R_B

$$\frac{\beta_1}{1+\beta_1} = \alpha_1$$

$$I_{C2} = \frac{\beta_2 (1+\beta_1)}{R_B} (V_{BB} - 2V_{be})$$

$$\begin{aligned} I_C = I_{C1} + I_{C2} &= \frac{\{ \beta_1 + \beta_2 (1+\beta_1) \} (V_{BB} - 2V_{be})}{R_B} \\ &= \frac{\{ \beta_1 + \beta_2 + \beta_1 \beta_2 \} (V_{BB} - 2V_{be})}{R_B} \end{aligned}$$

$$\begin{aligned}\beta_{\text{DUAL}} &= \frac{I_{C1} + I_{C2}}{I_{B1}} = \frac{\beta_1 I_{B1} + \beta_2 I_{B2}}{I_{B1}} \\ &= \frac{\beta_1 I_{B1} + \beta_2 I_{E1}}{I_{B1}} = \frac{\beta_1 I_{B1} + \beta_2 \frac{I_{C1}}{\alpha_1}}{I_{B1}} \\ &= \frac{\beta_1 I_{B1} + \beta_2 (1 + \beta_1) I_{B1}}{I_{B1}} = \beta_1 + \beta_2 + \beta_1 \beta_2\end{aligned}$$

IF THE TRANSISTORS ARE IDENTICAL

$$\beta_1 = \beta_2 = \beta$$

$$\beta_{\text{DUAL}} = \beta + \beta + \beta^2 = \beta(2 + \beta) \approx \beta^2$$

* TRANSISTORS MUST BE IN THE ACTIVE REGION!